

» Applications

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

» Product Summary

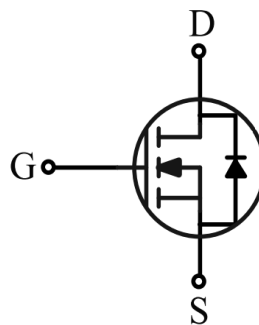
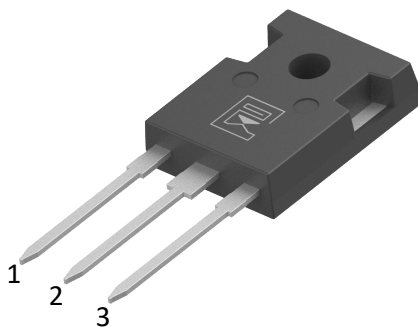
V_{DS}	430	V
I_D	11	A
$R_{DS(ON)}, Typ@10V$	0.47	Ω
Q_g	20	nC

» Features

- Low $R_{DS(ON)}$
- Ultra Low Gate Charge
- RoHS Compliant
- 100% UIS and RG Tested



TO-247S



Gate: 1
 Drain: 2
 Source: 3

» Package Marking and Ordering Information

Ordering code	Marking	Package	Packaging	Min. package quantity
MSIRF11N45	MSIRF11N45	TO-247S	Tube	450

» Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DS}	430	V
Gate-Source Voltage	V_{GS}	±30	V
Continuous Drain Current Tc=25°C (Note 1)	I_D	11	A
Continuous Drain Current Tc=100°C (Note 1)		6.8	
Drain Current-Pulsed (Note 1)	I_{DM}	44	A
Total Dissipation	P_D	96	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55-150	°C
Single Pulse Avalanche Energy (Note 2)	E_{AS}	450	mJ

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

» Thermal Characteristics

Parameter	Symbol	Max	Unit
Maximum Junction-to-Case	$R_{\theta JC}$	1.3	°C/W
Maximum Junction-to-Ambient	$R_{\theta JA}$	60	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD}=50V$, $T_{ch}=25^{\circ}C$ (initial), $I_{AS}=11A$, $R_g=25\Omega$.

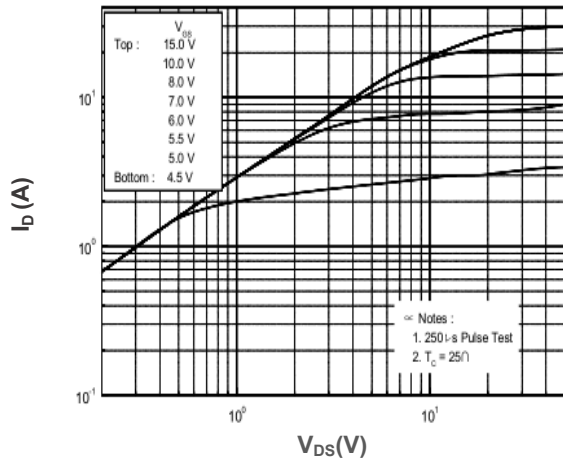
Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Electrical Characteristics (Tc=25°C unless otherwise noted)

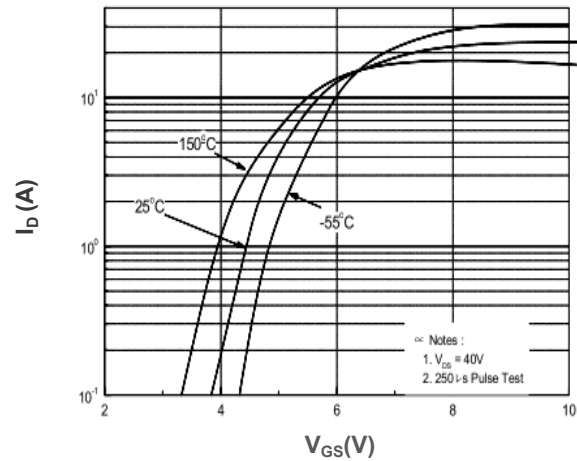
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static Parameters						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	430	-	-	V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =430V,V _{GS} =0V	-	-	1	uA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±30V,V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} ,I _D =250uA	2.0	3.0	4.0	V
Drain-Source On Resistance	R _{DS(ON)}	V _{GS} =10V,I _D =5.5A	-	0.47	0.50	Ω
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V, f=1.0MHz	-	1120	-	pF
Output Capacitance	C _{oss}		-	118	-	pF
Reverse Transfer Capacitance	C _{rss}		-	10	-	pF
Gate Resistance	R _g	V _{DS} =0V,V _{GS} =0V, f=1.0MHz	-	2	-	Ω
Switching Paramters						
Turn-On Delay Time	t _{d(on)}	V _{DS} =250V,I _D =11A, V _{GS} =10V,R _G =25Ω	-	32	-	ns
Turn-On Rise Time	t _r		-	28	-	ns
Turn-Off Delay Time	t _{d(off)}		-	90	-	ns
Turn-Off Rise Time	t _f		-	50	-	ns
Total Gate Charge	Q _g	V _{DS} =320V,I _D =11A, V _{GS} =10V	-	20	-	nC
Gate-Source Charge	Q _{gs}		-	6.5	-	nC
Gate-Drain Charge	Q _{gd}		-	4.5	-	nC
Source-Drain Characteristics						
Max. Diode Forward Cuurent	I _S		-	-	11	A
Max. Pulsed Forward Cuurent	I _{SM}		-	-	44	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =11A	-	0.86	1.5	V
Reverse Recovery Time	t _{rr}	V _R =320V,I _F =11A, di/dt=100A/us	-	320	-	ns
Reverse Recovery Charge	Q _{rr}		-	3.2	-	μC



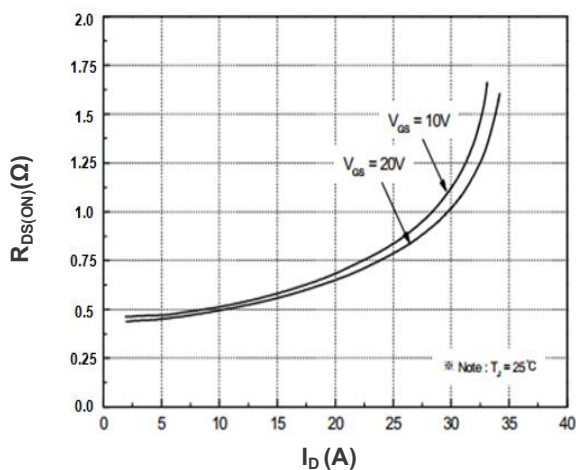
Characteristics Curves



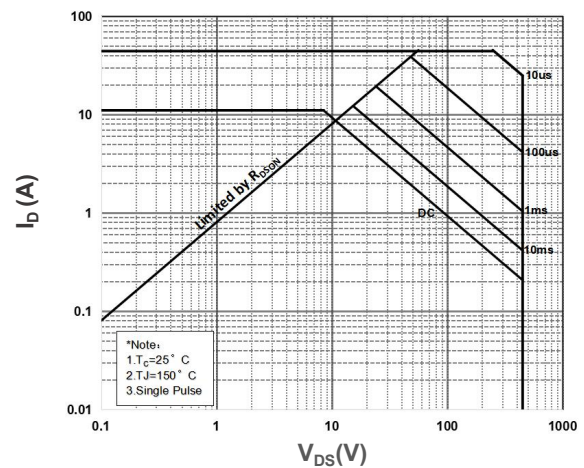
Output Characteristics



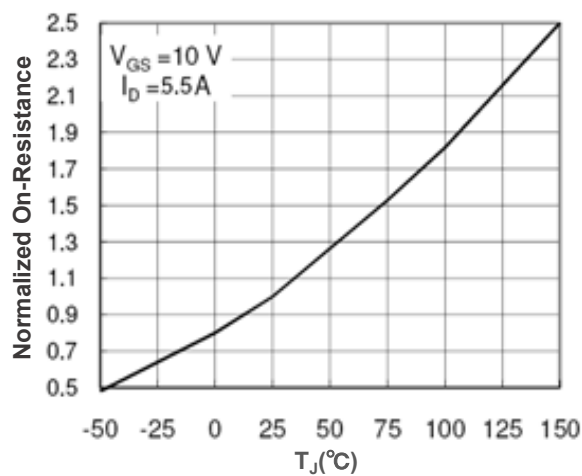
Transfer Characteristics



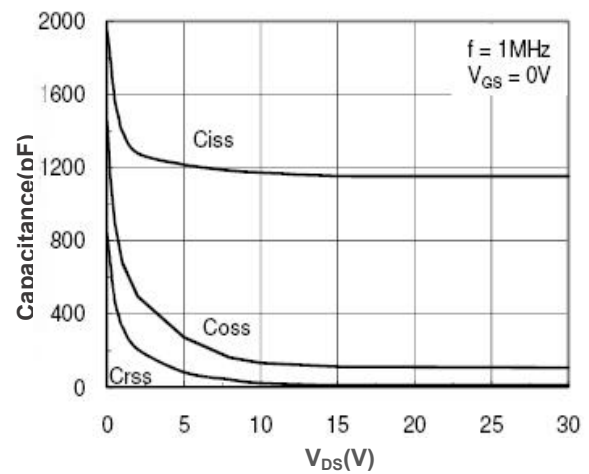
On Resistance Vs Drain Current



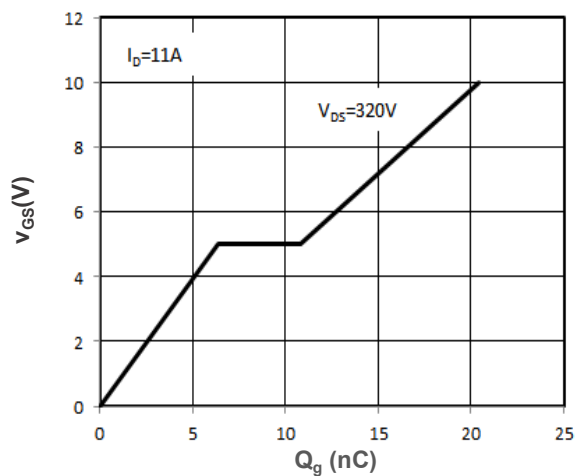
Safe Operating Area



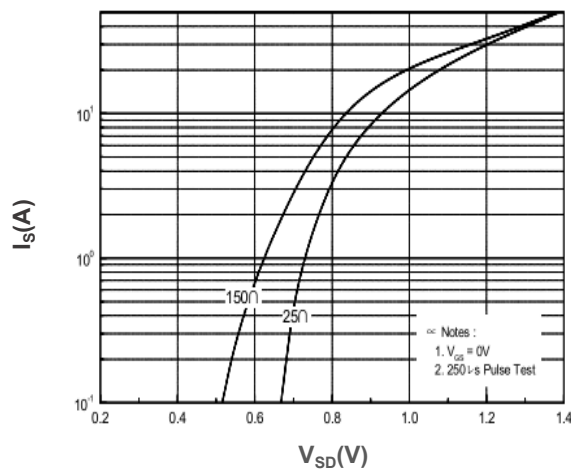
Rdson-JunctionTemperature



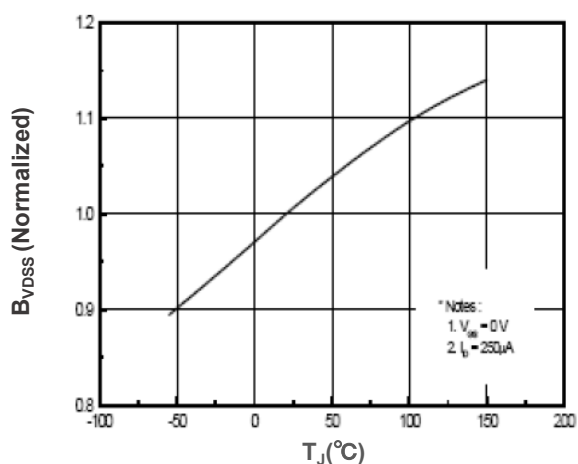
Capacitance



Gate Charge Waveform



Source-Drain Diode Forward Voltage



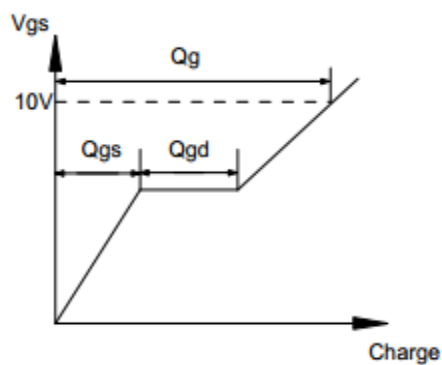
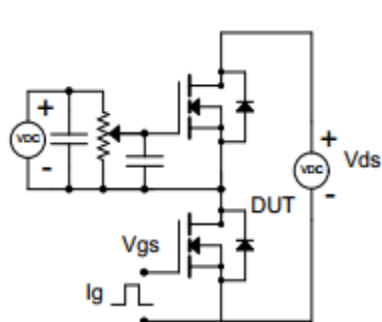
Breakdown Voltage Vs Junction Temperature

Note : The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

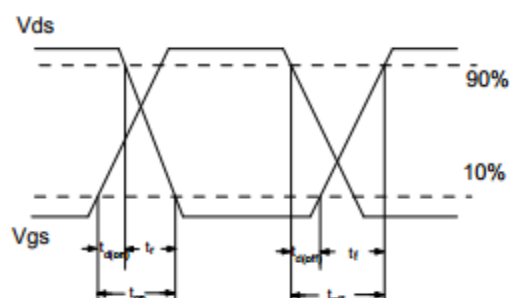
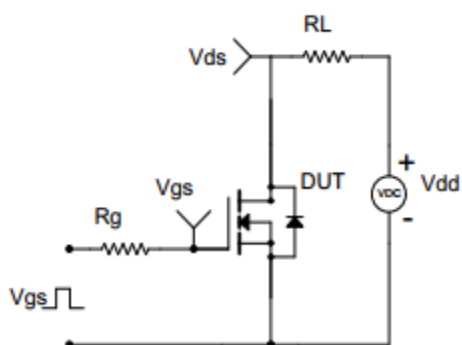


Test Circuit & Waveform

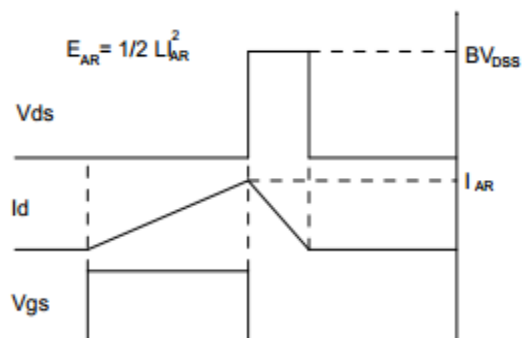
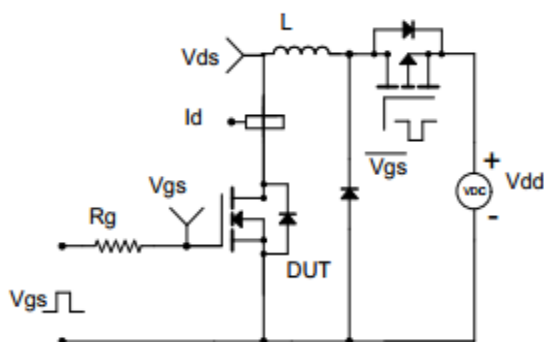
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveform





TO-247S Package Dimensions

Unit: mm

Symbol	Min	Nom	Max	Symbol	Min	Nom	Max
A	4.80	5.00	5.20	E1	13.00		13.60
A1	2.20	2.40	2.60	E2	5.00		5.50
A2	1.40	1.50	1.60	E3	1.90		2.60
b	1.07	1.20	1.33	e	5.25	5.45	5.65
b2	1.90	2.10	2.30	L	19.50	20.00	20.50
b4	2.90	3.10	3.30	L1	4.00	4.20	4.40
c	0.52	0.60	0.68	ΦP	3.50	3.70	3.90
D	20.80	21.00	21.20	ΦP1	7.00		7.40
D1	16.15		16.95	S	6.00	6.10	6.30
E	15.20	15.70	16.20				

